

Leading Innovation >>>

Toshiba Memory America, Inc.

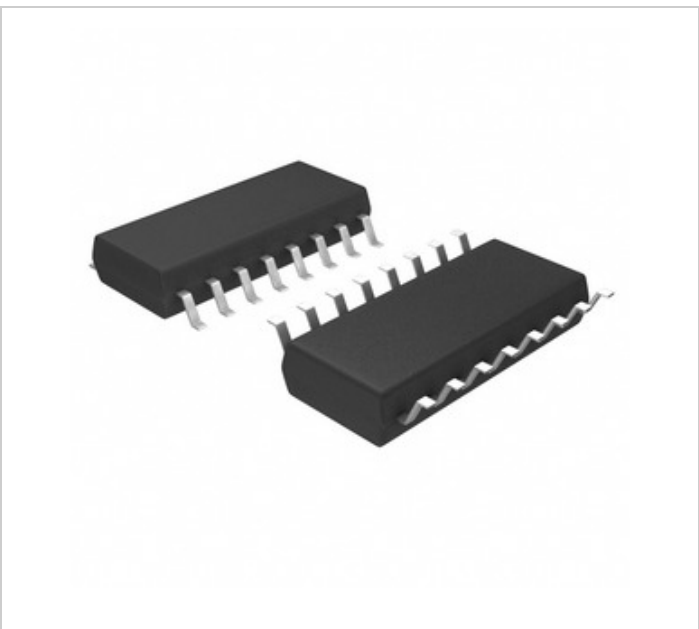


Image may be representation. See specifications for product details.

TC58CYG0S3HQAIE

Part Number:	TC58CYG0S3HQAIE
Manufacturer/Brand:	Toshiba Memory America, Inc.
Product description	IC FLASH 1G SPI 104MHZ 16SOP
Datasheets:	 TC58CYG0S3HQAIE.pdf
RoHs Status	 Lead free / RoHS Compliant
Stock Condition	4718 pcs stock
Ship From	Hong Kong
Shipment Way	DHL/Fedex/TNT/UPS/EMS

REQUEST FOR QUOTATION

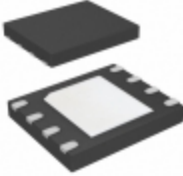
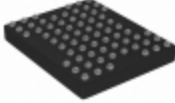
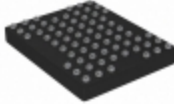
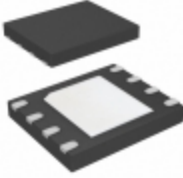
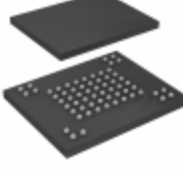
Specifications of TC58CYG0S3HQAIE

PART NUMBER	TC58CYG0S3HQAIE
MANUFACTURER	Toshiba Memory America, Inc.
DESCRIPTION	IC FLASH 1G SPI 104MHZ 16SOP
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
QUANTITY AVAILABLE	4718 pcs
DATA SHEET	 TC58CYG0S3HQAIE.pdf
WRITE CYCLE TIME - WORD, PAGE	-
VOLTAGE - SUPPLY	1.7 V ~ 1.95 V
TECHNOLOGY	FLASH - NAND (SLC)
SUPPLIER DEVICE PACKAGE	16-SOP
SERIES	-
PACKAGING	Tray
PACKAGE / CASE	16-SOIC (0.295", 7.50mm Width)
OTHER NAMES	TC58CYG0S3HQAIEY0J TC58CYG0S3HQAIEYCJ
OPERATING TEMPERATURE	-40°C ~ 85°C (TA)
MOUNTING TYPE	Surface Mount
MOISTURE SENSITIVITY LEVEL (MSL)	3 (168 Hours)
MEMORY TYPE	Non-Volatile
MEMORY SIZE	1Gb (128M x 8)
MEMORY INTERFACE	SPI
MEMORY FORMAT	FLASH
LEAD FREE STATUS / ROHS STATUS	Lead free / RoHS Compliant
DETAILED DESCRIPTION	FLASH - NAND (SLC) Memory IC 1Gb (128M x 8) SPI 104MHz 155µs 16-SOP
CLOCK FREQUENCY	104MHz
ACCESS TIME	155µs

Related Tags

Toshiba Memory America, Inc. TC58CYG0S3HQAIE	TC58CYG0S3HQAIE Distributor	TC58CYG0S3HQAIE Supplier
TC58CYG0S3HQAIE Price	TC58CYG0S3HQAIE Pictures	TC58CYG0S3HQAIE Image
TC58CYG0S3HQAIE PDF Datasheet	TC58CYG0S3HQAIE Download Datasheet	TC58CYG0S3HQAIE Datasheet
TC58CYG0S3HQAIE Stock	Buy TC58CYG0S3HQAIE	Buy Toshiba Memory America, Inc. TC58CYG0S3HQAIE
Toshiba Memory America, Inc. TC58CYG0S3HQAIE	Toshiba Memory America, Inc. Supplier	Toshiba Memory America, Inc. Distributor
Toshiba Memory America, Inc. TC58CYG0S3HQAIE		

Related Products

Leading Innovation >>> TC58CVG1S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 2GB SERIAL NAND 24NM WSON 1.8V In stock: 20305 pcs RFQ	Leading Innovation >>> TC58CVG0S3HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 16SOP In stock: 6477 pcs RFQ
 TC58NVG0S3HTA00 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G PARALLEL 48TSOP I In stock: 28754 pcs RFQ	 TC58CVG2S0HRAIG Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G SPI 104MHZ 8WSON In stock: 16041 pcs RFQ
Leading Innovation >>> TC58CYG2S0HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 4GB SERIAL NAND 24NM WSON 1.8V In stock: 20760 pcs RFQ	 TC58BYG2S0HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G PARALLEL 67VFBGA In stock: 16088 pcs RFQ
Leading Innovation >>> TC58CVG2S0HQAIE Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 4G SPI 104MHZ 16SOP In stock: 5981 pcs RFQ	Leading Innovation >>> TC58CYG0S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 1GB SERIAL NAND 24NM WSON 1.8V In stock: 25461 pcs RFQ
 TC58NVG0S3HBAI6 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G PARALLEL 67VFBGA In stock: 26231 pcs RFQ	 TC58CVG0S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G SPI 104MHZ 8WSON In stock: 21309 pcs RFQ
Leading Innovation >>> TC58CVG1S3HRAIG Manufacturers: Toshiba Memory America, Inc. Description: 2GB SERIAL NAND 24NM WSON 3.3V In stock: 20038 pcs RFQ	 TC58NVG0S3HBAI4 Manufacturers: Toshiba Memory America, Inc. Description: IC FLASH 1G PARALLEL 63TFBGA In stock: 28717 pcs RFQ